

- Delay Elements for Generating Delay Lines
- Inverting and Non-inverting Elements
- Buffer NAND Elements Rated at IOL of 12/24 mA
- PNP Inputs Reduce Fan-In (I_{IL} = -0.2 mA MAX)
- Worst Case MIN/MAX Delays Guaranteed Across Temperature and V_{CC} Ranges

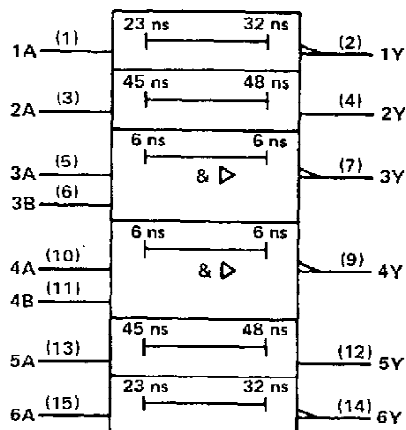
description

These 'LS31 delay elements are intended to provide well-defined delays across both temperature and V_{CC} ranges. Used in cascade, a limitless range of delay gating is possible.

All inputs are PNP with I_{IL} MAX of -0.2 mA. Gates 1, 2, 5, and 6 have standard Low-Power Schottky output sink current capability of 4 and 8 mA IOL. Buffers 3 and 4 are rated at 12 and 24 mA.

The SN54LS31 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74LS31 is characterized for operation from 0°C to 70°C.

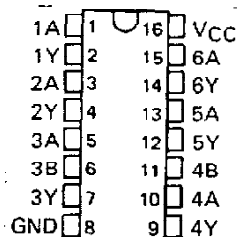
logic symbol†



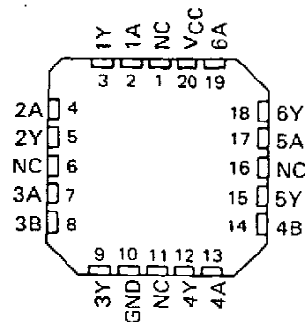
† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for D, J, N, and W packages.

SN54LS31 . . . J OR W PACKAGE
SN74LS31 . . . D OR N PACKAGE
(TOP VIEW)



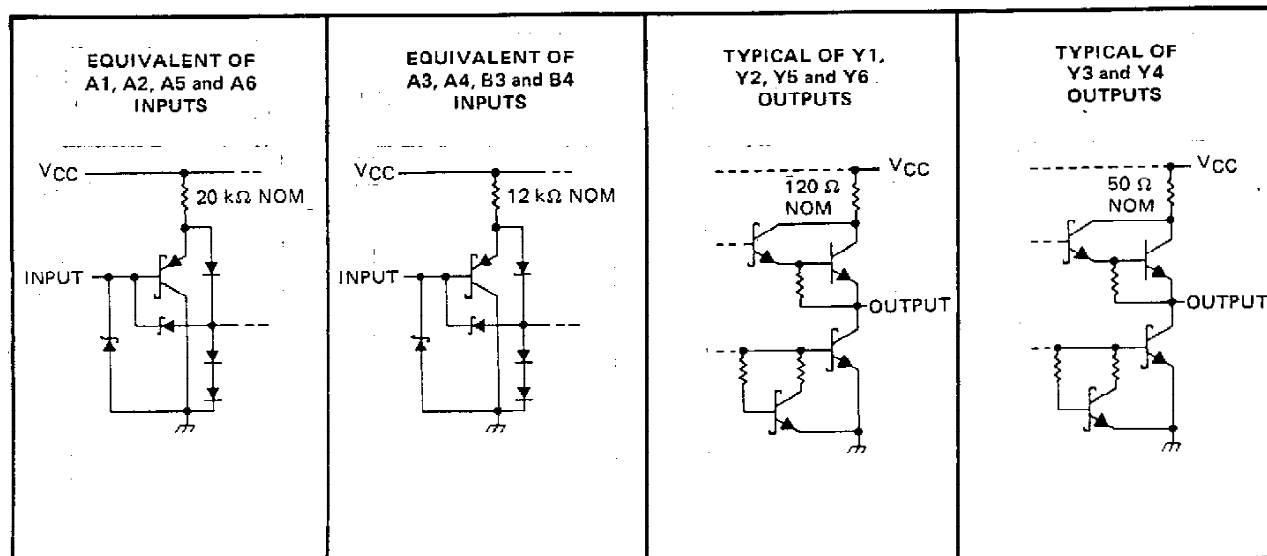
SN54LS31 . . . FK PACKAGE
(TOP VIEW)



NC - No internal connection

SN54LS31, SN74LS31 DELAY ELEMENTS

Delay Element	Logic	Typical Delays			Rated I_{OL}
		t_{PLH}	t_{PHL}	AVG.	
Gates 1 and 6	Inverting	32 ns	23 ns	27.5 ns	4 and 8 mA
Gates 2 and 5	Non-Inverting	45 ns	48 ns	46.5 ns	4 and 8 mA
Buffers 3 and 4	2-Input NAND	6 ns	6 ns	6 ns	12 and 24 mA



absolute maximum ratings over operating free air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (See Note 1)	7 V
Input voltage, V_I : All inputs	7 V
Operating free-air temperature range: SN54LS31	– 55° C to 125° C
SN74LS31	0° C to 70° C
Storage temperature range	– 65° C to 150° C

NOTE 1: Voltage values are with respect to network ground terminal.

recommended operating conditions

		SN54LS31			SN74LS31			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.7			0.8	V
I_{OH}	High-level output current			– 1.2			– 1.2	mA
				– 0.4			– 0.4	
I_{OL}	Low-level output current			12			24	mA
				4			8	
T_A	Operating free-air temperature	– 55		125	0		70	°C

TEXAS
INSTRUMENTS

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SN54LS31, SN74LS31 DELAY ELEMENTS

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			SN54LS31			SN74LS31			UNIT
				MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V _{IK}	V _{CC} = MIN, I _I = -18 mA					-1.5			-1.5	V
V _{OH}	V _{CC} = MIN, V _{IH} = 2 V, V _{IL} = MAX	Y3, Y4	I _{OH} = -1.2 mA	2.4	3.1		2.4	3.1		V
		Others	I _{OH} = -0.4 mA	2.5	3.1		2.7	3.1		
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, V _{IL} = MAX	Y3, Y4	I _{OL} = 12 mA		0.25	0.4		0.25	0.4	V
			I _{OL} = 24 mA					0.35	0.5	
		Others	I _{OL} = 4 mA		0.25	0.4		0.25	0.4	
			I _{OL} = 8 mA					0.35	0.5	
I _I	V _{CC} = MAX, V _I = 7 V					0.1			0.1	mA
I _{IH}	V _{CC} = MAX, V _I = 2.7 V					20			20	μA
I _{IL}	V _{CC} = MAX, V _I = 0.4 V					-0.2			-0.2	mA
I _{OS} §	V _{CC} = MAX, A3, A4, B3, B4 = 0 V	Y3, Y4		-30		-130	-30		-130	mA
	V _{CC} = MAX, A1, A6 = 0 V, A2, A5 = 4.5 V	Y1, Y2, Y5, Y6		-20		-100	-20		-100	
I _{CC}	I _{CC} H	V _{CC} = MAX, A2, A5 = 4.5 V, all other inputs 0 V			2.3	4		2.3	4	mA
	I _{CC} L	V _{CC} = MAX, A2, A5 = 0 V, all other inputs 4.5 V			13	20		13	20	

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time and the duration of the short-circuit should not exceed one second.

switching characteristics, (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LS31			SN74LS31			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
t _{PLH}	A1, A6	Y1, Y6	15		70	22		65	ns
t _{PHL}			9		50	13		45	
t _{PLH}	A2, A5	Y2, Y5	22		90	31		80	ns
t _{PHL}			20		105	30		95	
t _{PLH}	A3, B3, A4, Y4	Y3, Y4	2		20	2		15	ns
t _{PHL}			2		20	2		15	

NOTE 2: V_{CC} = MIN to MAX

R_L = 667 Ω, C_L = 45 pF for Y3 and Y4.

R_L = 2 kΩ, C_L = 15 pF for Y1, Y2, Y5 and Y6.

T_A = MIN to MAX

Load circuits and voltage waveforms are shown in Section 1.

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